



Aktuelles Experiment:

noname.rcp

Modellbeschreibung

Number	Layer Name	Thickness [nm]	Refr. Index [632.8 nm]	Fitted
0	Air	-	1.000	no
1	NoName0	76.07	1.492	yes
2	Silicon DUV-NI	R -	3.874	no

Fit parameter

Fit parameter	Fit result
[1,1] NoName0: Thickness [nm]	76.07
NoName0: N0	1.482

All parameter

Parameter	Value
[1] Wavelength [nm]	632.8
[1] Angle [°]	70.00
[1] Time [s]	0.0
[1] Temperature [°C]	23.5
[1] Sample rotation [°]	0.00
[1] Depol. D0	1.0000
[1] Depol. D1	0.0000
[1] Depol. D2	0.0000
[1] Beam diameter	4.00
[1] Aperture diameter	4.00
[1,1] Thickness variation	10.0
[1] Wavelength resolution (nm)	0.0
[1] Angle variation	3.0
[1] Angle offset [°]	0.00
[1] Wavelength Offset (nm)	0.00
[1] Wavelength Linear	1.00000
[1] Fraction Overlayer	1.000
[1] Backside Factor	1.000
Air: Refr. index	1.000
Air: Absorption	0.000
Air: N Offset	0.00000



Air: K Offset [1,1] NoName0: Thickness [nm] NoName0: N0 NoName0: N1 NoName0: N2 NoName0: K0 NoName0: K1 NoName0: K2 NoName0: K Offset NoName0: K Offset Silicon DUV-NIR: N Offset Silicon DUV-NIR: K Offset Pola.Pos. Pola.Offs. Ret.Axis Ret.Phase Eta Ana.Offs. Ana.Offs.Lin. Ana.Offs.Quadr. Psi Offs. Psi Lin. Psi Quadr. Delta Offs. Delta Lin.	0.00000 76.07 1.482 40.0 0.0 0.000 0.000 0.0000 0.00000 0.00000 0.00000 45.00 0.00 0
Delta Quadr.	0.00
MSE	0.73646692
MOL	5.7 50±555Z

Measured Data

RRM001-046 / Psi, Delta / Spectral range: 300.2 nm - 1050.0 nm / Angle of incidence: 60.00 $^{\circ}$ / 9/17/2019 3:09:14 PM



